

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lay bed ON Semiconductor and its officers, employees, ween if such claim alleges that ON Semiconductor was negligent regarding the d

FAIRCHILD SEMICONDUCTOR

FQPF7N65C N-Channel QFET[®] MOSFET

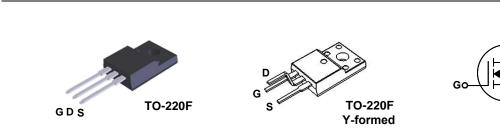
 $650~V, 7~A, 1.4~\Omega$

Description

This N-Channel enhancement mode power MOSFET is \bullet 7 A, 650 V, R_{DS(on)} = 1.4 Ω (Max.) @ V_{GS} = 10 V, I_D = 3.5 A produced using Fairchild Semiconductor®'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to . Low Crss (Typ. 12 pF) reduce on-state resistance, and to provide superior • 100% Avalanche Tested switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- Low Gate Charge (Typ. 28 nC)



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		FQPF7N65C / FQPF7N65CYDTU	Unit	
V _{DSS}	Drain-Source Voltage		650	V	
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		7 *	А	
	- Continuous (T _C = 100°C)		4.2 *	А	
I _{DM}	Drain Current - Pulsed	(Note 1)	28 *	А	
V _{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	212	mJ	
I _{AR}	Avalanche Current	(Note 1)	7	А	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	1.6	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.5	V/ns	
PD	Power Dissipation (T _C = 25°C)		52	W	
	- Derate above 25°C		0.42	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
T.	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		200	°C	
ΤL			300		
Drain current lim	ited by maximum junction temperature.				

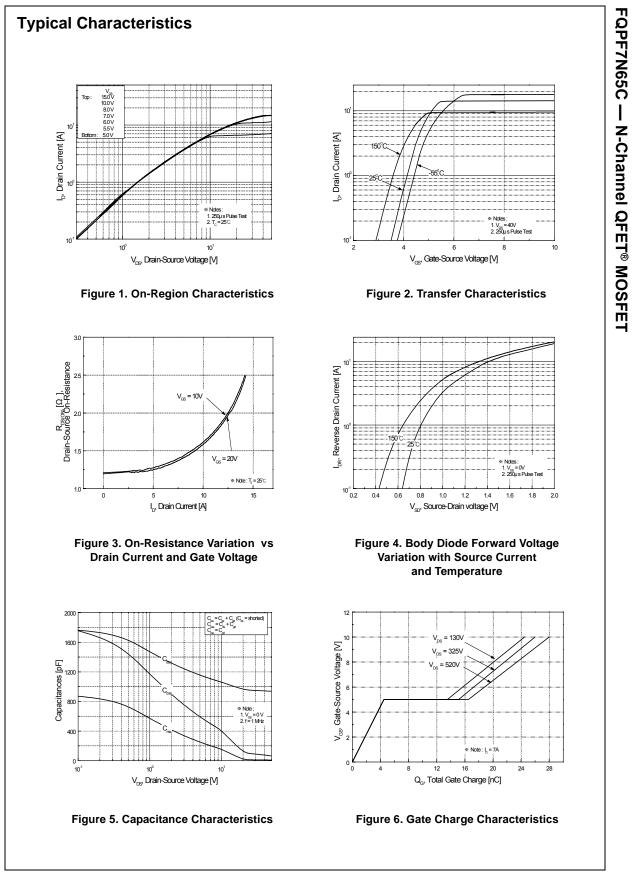
Thermal Characteristics

Symbol	Parameter	FQPF7N65C / FQPF7N65CYDTU	Unit
R _{0JC} Thermal Resistance, Junction-to-Case, Max.		2.4	°C/W
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

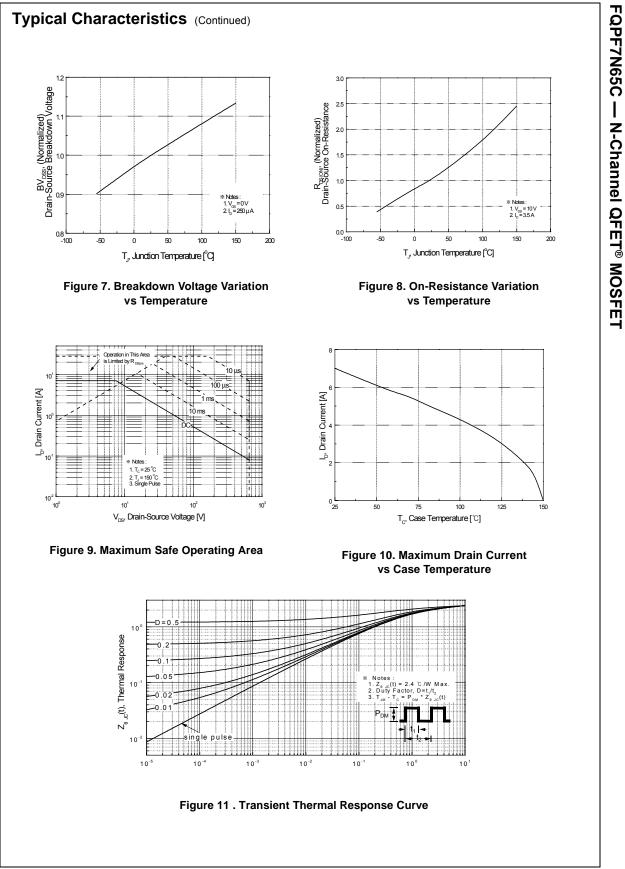
August 2013

D

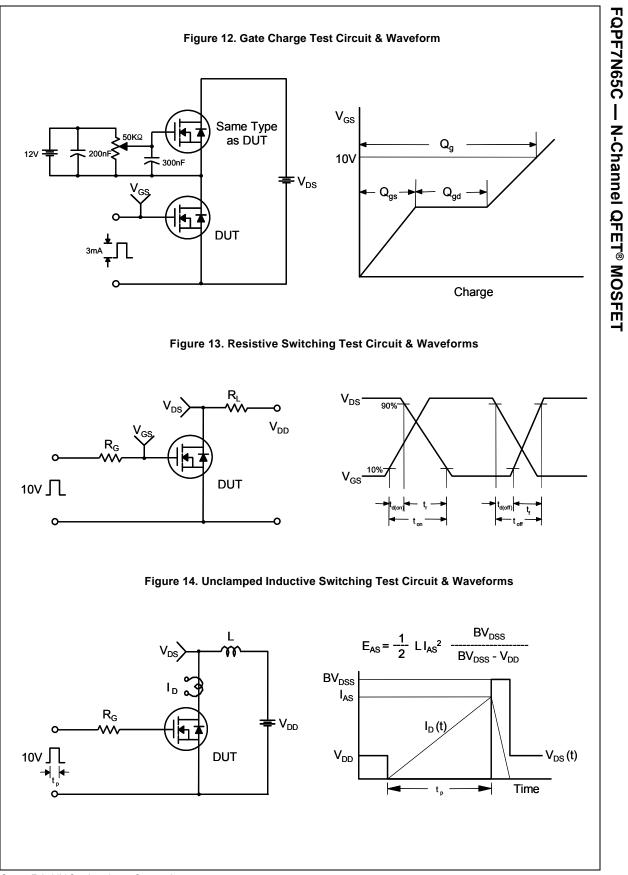
Device Marking		Device	Package	Package Reel Size		Tape Width		Quantity	
FQP	F7N65C	FQPF7N65C	TO-220F	-	-		5	50	
FQPF7N65C FQPF7N65CYDTU TO-2		TO-220F (Y-formed)	220F (Y-formed) -		-		50		
lectri	cal Cha	racteristics	= 25°C unless otherwise noted	4					
Symbol		Parameter	+	onditions	Min	Тур	Max	Unit	
Off Cha	racterist	ics							
BV _{DSS}		rce Breakdown Voltage	V _{GS} = 0 V, I _D = 2	250 μΑ	650			V	
ΔBV _{DSS} / ΔT _{.1}		n Voltage Temperature		ferenced to 25°C		0.8		V/°C	
I _{DSS}			V _{DS} = 650 V, V _G	_{3S} = 0 V			1	μA	
	∠ero Gate	Voltage Drain Current	V _{DS} = 520 V, T _C				10	μA	
I _{GSSF}	Gate-Bod	y Leakage Current, Forw	ard V_{GS} = 30 V, V_{DS}	_s = 0 V			100	nA	
I _{GSSR}	Gate-Bod	y Leakage Current, Reve	erse V_{GS} = -30 V, V_D	_S = 0 V			-100	nA	
On Cha	racterist	ics							
V _{GS(th)}		shold Voltage	$V_{DS} = V_{GS}, I_D =$	250 μΑ	2.0		4.0	V	
R _{DS(on)}	Static Drai On-Resist		V _{GS} = 10 V, I _D =	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$		1.2	1.4	Ω	
9 _{FS}	Forward T	ransconductance	V _{DS} = 40 V, I _D =	3.5 A		8		S	
C _{iss} C _{oss} C _{rss}	Input Cap Output Ca Reverse T		V _{DS} = 25 V, V _{GS} f = 1.0 MHz	_S = 0 V,		955 100 12	1245 130 16	pF pF pF	
	ng Char	acteristics			1			I	
t _{d(on)}	_	Delay Time	N/ 005 V/ I	V_{DD} = 325 V, I _D = 7A, R _G = 25 Ω		20	50	ns	
t _r	Turn-On F	•				50	110	ns	
t _{d(off)}	Turn-Off D	Jelay Time				90	190	ns	
t _f	Turn-Off F			(Note 4)		55	120	ns	
Qg	Total Gate	Charge	V _{DS} = 520 V, I _D	= 7A,		28	36	nC	
Q _{gs}	Gate-Sou	rce Charge	V _{GS} = 10 V			4.5		nC	
Q _{gd}	Gate-Drai	n Charge		(Note 4)		12		nC	
Drain S		ada Charactoristia	a and Maximum	Dotingo					
l _s	I	ode Characteristic					7	A	
's I _{SM}		Continuous Drain-Source Diode Forward Current Pulsed Drain-Source Diode Forward Current				28	A		
V _{SD}		rce Diode Forward Volta		7A			1.4	V	
t _{rr}		Recovery Time	$V_{GS} = 0 V, I_S = 1$			400		ns	
Q _{rr}		Recovery Charge	00 0	$v_{GS} = 0 v, r_S = 7A,$ dl _F / dt = 100 A/µs		3.3		μC	
							I	24	



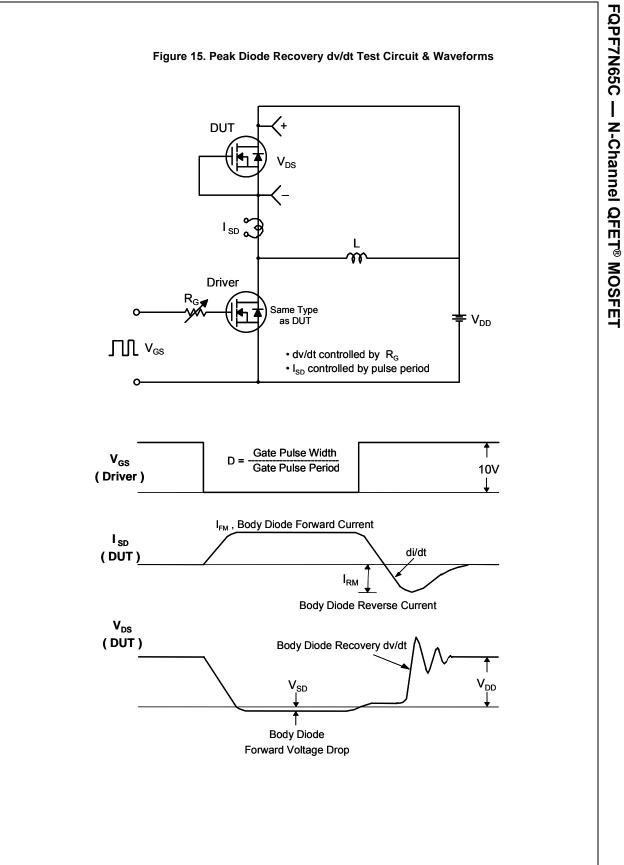
©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1

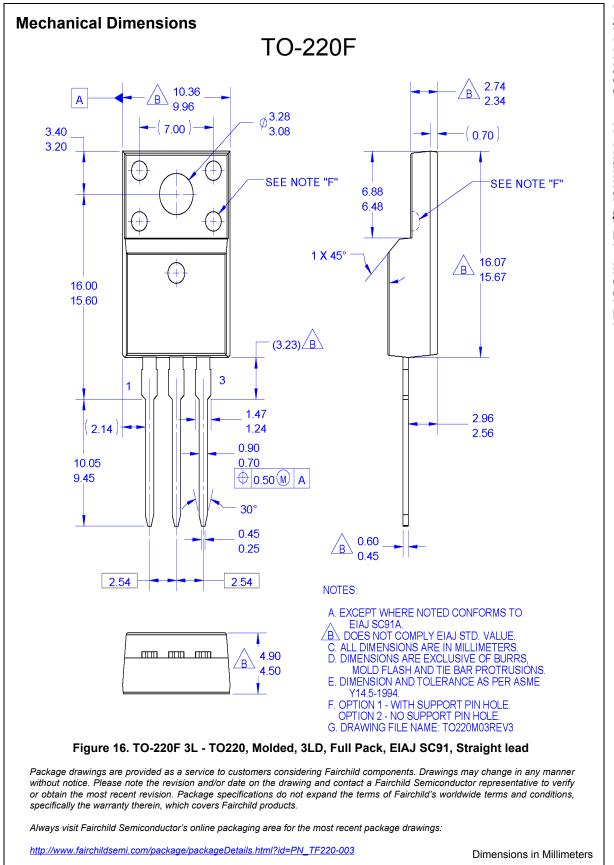


©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1

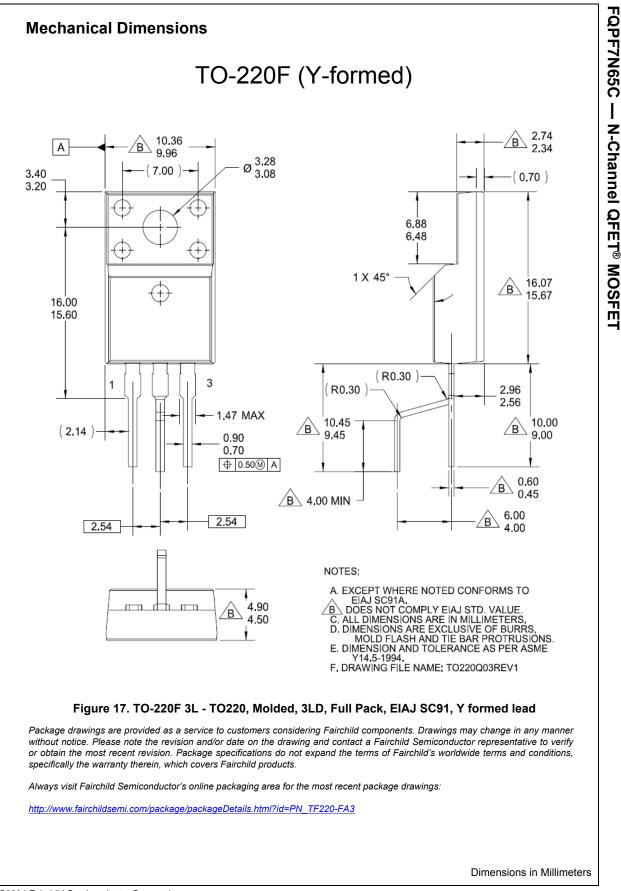


©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1





FQPF7N65C — N-Channel QFET[®] MOSFET





SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

 $(1)_{\mathbb{R}}$

PowerTrench[®]

2Cool [™] AccuPower [™] AX-CAP [®] * BitSiC [™] Build it Now [™] CorePLUS [™] CorePOWER [™] CROSSVOLT [™] CTL [™] CTL [™] Current Transfer Logic [™] DEUXPEED [®] Dual Cool [™] EcoSPARK [®] EfficentMax [™]
EfficentMax™ ESBC™

Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT® FAST® FastvCore™ FETBench™

F-PFS™ **FRFET**® Global Power ResourceSM Green Bridge™ Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX[™] **ISOPLANAR™** Marking Small Speakers Sound Louder and Better™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ mWSaver™ OptoHiT™ OPTOLOGIC[®] **OPTOPLANAR®**

FPS™

PowerXS™ Programmable Active Droop™ QFĔT QS™ Quiet Series™ RapidConfigure[™] тм Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START Solutions for Your Success™ SPM[®] STEALTH™ SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS[®] SyncFET™

Sync-Lock™ SYSTEM^{®*} GENERAL TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC[®] TriFault Detect™ TRUECURRENT®* µSerDes™ $\mathcal{N}_{\scriptscriptstyle{\mathsf{Ser}}}$ UHC® Ultra FRFET™

UniFET™ VCX™ VisualMax™ VoltagePlus[™]

XS™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS **Definition of Terms**

Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC